# NSN 5961-01-101-7048

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## Inclosure Material:

Metal

**Overall Length:** 

1.330 inches

## **Overall Diameter:**

Between 0.570 inches and 0.610 inches

## **End Application:**

Ifv (xm2) cfv (xm3)

## **Mounting Facility Quantity:**

1

## Internal Configuration:

Junction contact

## **Mounting Method:**

Threaded stud

## Overall Width Across Flats:

Between 0.667 inches and 0.687 inches

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

120.0 collector to base voltage/static/emitter open and 100.0 collector to emitter voltage/static/base open and 8.0 emitter to base voltage,

static, collector open

## **Current Rating Per Characteristic:**

30.00 amperes source cutoff current and 5.00 amperes source cutoff current

## Power Rating Per Characteristic:

125.0 watts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

## **Special Features:**

Junction pattern arrangement: npn

## Nuclear Hardness Critical Feature:

Hardened

## **Test Data Document:**

19200-12271997 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

## Terminal Type And Quantity:

3 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

Fiig:

A110a0